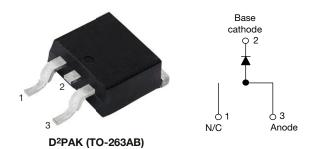


Vishay Semiconductors

High Performance Schottky Rectifier, 10 A



PRIMARY CHARACTERISTICS					
I _{F(AV)} 10 A					
V _R	35 V, 45 V				
V _F at I _F	0.57 V				
I _{RM}	15 mA at 125 °C				
T _J max.	150 °C				
E _{AS}	8 mJ				
Package	D ² PAK (TO-263AB)				
Circuit configuration	Single				

FEATURES

- 150 °C T_J operation
- TO-220 and D²PAK packages
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES UNITS								
I _{F(AV)}	Rectangular waveform	10	٨					
I _{FRM}	T _C = 135 °C	20	— A					
V _{RRM}		35/45	V					
I _{FSM}	t _p = 5 μs sine	1060	A					
V _F	10 A _{pk} , T _J = 125 °C	0.57	V					
TJ	Range	-65 to +150	C°					

VOLTAGE RATINGS								
PARAMETER SYMBOL VS-MBRB1035-M3 VS-MBRB1045-M3 UNITS								
Maximum DC reverse voltage	V _R	35	45	V				
Maximum working peak reverse voltage	V _{RWM}		45	v				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CON	VALUES	UNITS				
Maximum average forward current	I _{F(AV)}	T_{C} = 135 °C, rated V_{R}	T _C = 135 °C, rated V _R					
Peak repetitive forward current	I _{FRM}	Rated V _R , square wave, 20 kł	Hz, T _C = 135 °C	20				
Non-repetitive surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1060	А			
		Surge applied at rated load conditions halfwave, single phase, 60 Hz		150				
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 4 mH		8	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		2	А			

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COMPLIANT

HALOGEN

FREE



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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		20 A	$T_J = 25 \ ^{\circ}C$	0.84		
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	T.I = 125 °C	0.57	V	
		20 A	1j=125 0	0.72		
Maximum instantaneous reverse	I _{BM} ⁽¹⁾	$T_J = 25 \text{ °C}$		0.1	mA	
current	IRM \''	T _J = 125 °C	T _J = 125 °C Rated DC voltage			
Threshold voltage	V _{F(TO)}			0.354	V	
Forward slope resistance	r _t	$T_J = T_J maximum$		17.6	mΩ	
Maximum junction capacitance	CT	V _R = 5 V _{DC} (test signal rat °C	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz), 25 $^\circ\text{C}$		pF	
Typical series inductance	L _S	Measured from top of terminal to mounting plane		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R	Rated V _R			

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction tempera	ature range	TJ		-65 to 150	°C		
Maximum storage tempera	ture range	T _{Stg}		-65 to 175	C		
Maximum thermal resistan junction to case	ce,	R _{thJC}	DC operation	2.0	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased (Only for TO-220)	0.50	0/10		
Approvimate weight				2	g		
Approximate weight				0.07	oz.		
Mounting torque	minimum			6 (5)	kgf · cm		
maximum				12 (10)	(lbf ⋅ in)		
Marking device			Case style D ² PAK (TO-263AB)	MBRB1035			
			Case Sigle D-FAR (10-203AB)	MBRE	31045		



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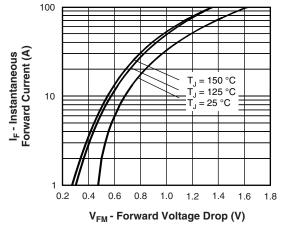


Fig. 1 - Maximum Forward Voltage Drop Characteristics

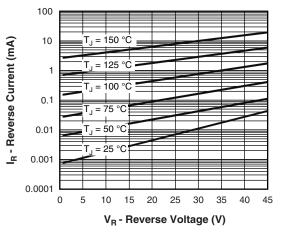


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

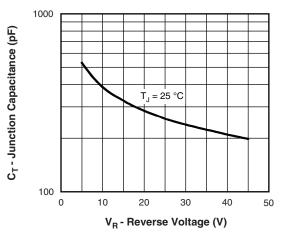


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

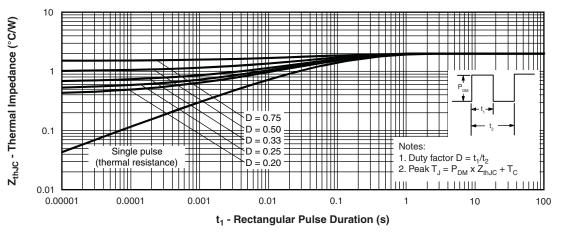
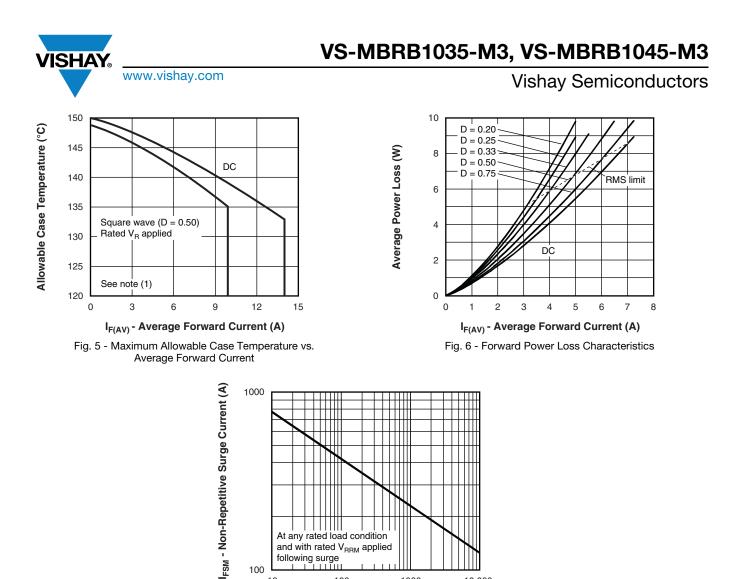


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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At any rated load condition and with rated $\mathrm{V}_{\mathrm{RRM}}$ applied

100

 t_p - Square Wave Pulse Duration (µs) Fig. 7 - Maximum Non-Repetitive Surge Current

1000

10 000

following surge

100 10

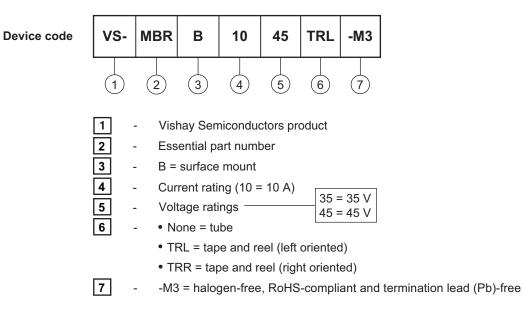
Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; $I_R at V_{R1} = rated V_R$



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ORDERING INFORMATION TABLE



ORDERING INFORMATION								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-MBRB1035-M3	50	1000	Antistatic plastic tubes					
VS-MBRB1035TRR-M3	800	800	13" diameter reel 13" diameter reel					
VS-MBRB1035TRL-M3	800	800						
VS-MBRB1045-M3	50	1000	Antistatic plastic tubes					
VS-MBRB1045TRR-M3	800	800	13" diameter reel					
VS-MBRB1045TRL-M3	800	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96164					
Part marking information	www.vishay.com/doc?95444				
Packaging information	www.vishay.com/doc?96424				
SPICE model	www.vishay.com/doc?95293				

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D²PAK

DIMENSIONS in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STNDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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